### 捷多邦,专业PCB打样工厂,24小时加急出货

#### 查询BD9560MUV供应商

## ROHM

STRUCTURE TYPE PRODUCT SERIES FEATURES

Silicon Monolithic Integrate Circuit

step down DC/DC converter controller for mobile PC

**BD9560MUV** 

·DC/DC converter controller.

·Build in MOS-FETs driver

·5-bit DAC for output voltage.

## O ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

Parameter	Symbol	Limits	Unit
Input voltage 1	VCC	7 *1*2	V
Input voltage 2	PVCC	7 *1*2	V
Input voltage 3	VIN	35 *1*2	V
BTS voltage	BTS	35 *1*2	V
BTS to SW voltage	BTS-SW	7 *1*2	V
HG to SW voltage	HG-SW	7 *1*2	V
Logic input voltage	LG	PVCC	V
VREF voltage	VREF	VCC	V
VRON input voltage	VRON	7 *1	V
Logic input voltage	CL/SCP/SS/TON/SLLM/VID4-0 PWRGD_C/DAC_C	VCC	v
Logic output voltage 1	PWRGD	7	V
Logic output voltage 2	SUS_OUT	VCC	V
Power dissipation 1	Pd1	0.38 *3	W
Power dissipation 2	Pd2	0.88 *4	W
Operating temperature range	Topr	-10~+100	°C
Storage temperature range	Tstg	-55~+150	°C
Junction temperature range	Tjmax	+150	°C

\*2 Instantaneous surge voltage, back electromotive force and voltage under less than 10% duty cycle. \*3 Reduced by 3.0mW for each increase in Ta of 1°C over 25°C (when don't mounted on a heat radiation board ) \*4 Reduced by 7.0mW for increase in Ta of 1°C over 25°C. (when mounted on a board 70.0mm × 70mm × 1.6mm Glass-epoxy PCB.))

## O OPERATION SUPPLY VOLTAGE RANGE (Ta=25°C)

Parameter	Symbol	Minimum	Maximum	Unit
Input voltage 1	VCC	4.5	5.5	V
Input voltage 2	PVCC	4.5	5.5	V
Input voltage 3	VIN	4.5	25	V
BTS voltage	BTS	4.5 ·	30	V
SW voltage	SW	-2	25	V
BTS to SW voltage	BTS-SW	4.5	5.5	V
VRON input voltage	VRON	-0.3	5.5	V
Logic input voltage	CL/SCP/SS/TON/SLLM/VID4-0 PWRGD_C/DAC_C	-0.3	VCC+0.3	v
Logic output voltage 1	PWRGD	-0.3	5.5	V
Logic output voltage 2	SUS_OUT	-0.3	VCC	V

★ This product is not designed for protection against radioactive rays.

Status of this document

The Japanese version of this document is the official specification.

This translated version is intended only as a reference, to aid in understanding the official version.

If there are any differences between the original and translated versions of this document, the official Japanese language version takes priority.



1/4

# ROHM

O\_ELECTRICAL CHARACTERISTICS (Unless otherwise noted, Ta=25°C, VCC=5V,VIN=12V, VRON=5V,VDAC=1.2811V,SLLM=0V)

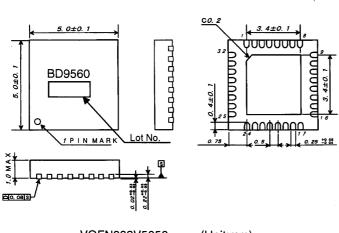
					V=12V, VRC	DN=5V,VDAC=1.2811V,SLLM=0V)
Parameter	Symbol		standard valu		Unit	Conditions
	- Cymbol	MIN.	TYP.	MAX.	onit	Conditionis
[Total block]						
VCC bias current		-	4	10	mA	VCC=5V
VIN bias current	ICC_VIN	-	20	50	uA	VIN=12V
VCC shut down mode current	IST VCC	-	0	10	uA	VRON=0V
VIN shut down mode current	IST_VIN	-	0	10	uA	VRON=0V
VRON low voltage	VRON_L	GND		0.8	V	
VRON high voltage	VRON_H	2.3	-	5.5	<u>v</u>	
VRON bias current	IVRON_	2.3	10	20		VRON=5V
		-	10	20	uA	VHON=5V
[Reference voltage block]					<b></b>	
Reference output voltage	VREF	2.475	2.500	2.525	V	IREF=0 to 100uA
Maximum source current	IREF_source	0.5	-	-	mA	
Line regulation	Reg.l	-	0.1	0.3	%/V	VCC=4.5 to 5.5V
Load regulation	Reg.L	-	5	20	mV	IREF=0 to 0.5mA
[Over voltage protection block]						
Threshold voltage	VOVPL	1.400	1.500	1.600	V	
Hysterisys voltage	VOVPH	50	150	250	mV	
[Under voltage lock-out block]			100			
VCC input threshold voltage		4.0	4.1	4.2	V	VCC: Sweep up
VCC hysterics voltage	dVCC_UVLO	50	100	200	mV	VCC: Sweep down
[VID block]	1 1000 11					T
VID input high voltage	VVID_H	2.0	-	VCC	V	
VID input low voltage	VVID_L	GND	-	0.8	V	
VID bias current	IVID	-	0	1	uA	VVID=3.3V
DAC delay charge current	IDAC+	90	170	250	uA	
DAC output voltage	VDAC	1.2683	1.2811	1.2939	v	VID[0:4]=0V
[Error amplifier block]	1					
Output feed back voltage	VFB	VDAC-0.5%	VDAC	VDAC+0.5%	V	
[Current limit protection block]		1040-0.070	VERO	VDA0+0.570	v	
Current limit threshold	llim	22	30	38	mV	CL=0.48V
	VCL					CL=0.46V
CL adjustment range		0.2		1.5	V	
CL bias current	ICL	-	0	1	uA	CL=5V
[Load slope setup block]						
Offset voltage	VLS	-6	0	6	mV	
[Soft start block]						
SS Delay charge current	ISS	1.5	2.0	2.5	uA	
[Short circuit Protection]						•
SCP Delay charge current	ISCP	1.5	2.0	2.5	uA	
[SLLM block]	1					
Continuous mode threshold	Vthcon	GND	-	0.5	V	
		VCC-0.5		VCC	V	+
SLLM threshold	VthSL <sup>2</sup> M	VUU-0.5	-		<u> </u>	
[On time pulse width]	T			· · · ·		
On time pulse width	Fosc	250	350	450	ns	TON=1V
TON adjustment voltage	VTON	0.2	-	2.0	V	
TON bias current	ITON	-	0	1	uA	TON=5V
[OFF time width]						
Min off time	MinOff	0.25	0.5	1.0	us	
[Driver block]				. J.		
HG high side ON resistor	RonHGH	_	1	2	Ohm	Т
HG low side ON resistor	BonHGL	-	1	2	Ohm	
LG high side ON resistor	RonLGH	-	1	_		
				2	Ohm	
LG high side ON resistor	RonLGL	-	0.5	1	Ohm	
[Power good block]		1 1/010	1/510			
PWRGD Low threshold voltage	PGDLow	VDAC -400mV	VDAC -300mV	VDAC -200mV	v	
PWRGD High threshold voltage	PGDHigh	VDAC +100mV	VDAC +200mV	VDAC +300mV	v	
PWRGD Output voltage	VPWRGD		-	0.4	V	IPRGD=4mA
PWRGD Output leakage current	PGDLeak	-	-	10	uA	PWRGD=3.6V
PWRGD C Delay charge current	IPD	1.5	2.0	2.5		
		1.5	2.0	2.5	uA	



## ○ DAC code table

State	Enable	VID4	VID3	VID2	VID1	VID0	VCCGFX	VDAC	SUS OUT
	1	0	0	0	0	0	1.28750V	1.2811V	0
	1	0	0	0	0	1	1.26175V	1.2554V	0
	1	0	0	0	1	0	1.23600V	1.2298V	0
	1	0	0	0	1	1	1.21025V	1.2042V	0
es	1	0	0	1	0	0	1.18450V	1.1786V	0
Stat	1	0	0	1	0	1	1.15875V	1.1530V	0
e C	1	0	0	1	1	0	1.13300V	1.1273V	0
L L	1	0	0	1	1	1	1.10725V	1.1017V	0
ů.	1	0	1	0	0	0	1.08150V	1.0761V	0
Render Performance States	1	0	1	0	0	1	1.05575V	1.0505V	0
Pel	1	0	1	0	1	0	1.03000V	1.0249V	0
er	1	0	1	0	1	1	1.00425V	0.9992V	0
pu	1	0	1	1	0	0	0.97850V	0.9736V	0
Re	1	0	1	1	0	1	0.95275V	0.9480V	0
	1	0	1	1	1	0	0.92700V	0.9224V	0
	1	0	1	1	1	1	0.90125V	0.8967V	0
	1	1	0	0	0	0	0.87550V	0.8711V	0
	1	1	0	0	0	1	0.84975V	0.8455V	0
	1	1	0	0	1	0	0.82400V	0.8199V	1
	1	1	0	0	1	1	0.79825V	0.7943V	1
	1	1	0	1	0	0	0.77250V	0.7686V	1
	1	1	0	1	0	1	0.74675V	0.7430V	1
tes	1	1	0	1	1	0	0.72100V	0.7174V	1
States	1	1	0	1	1	1	0.69525V	0.6918V	1
d	1	1	1	0	0	0	0.66950V	0.6662V	1
Sleep	1	1	1	0	0	1	0.64375V	0.6405V	1
S S	1	1	1	0	1	0	0.61800V	0.6149V	1
de	1	1	1	0	1	1	0.59225V	0.5893V	1
Render	1	1	1	1	0	0	0.56650V	0.5637V	1
	1	1	1	1	0	1	0.54075V	0.5380V	1
	1	1	1	1	1	0	0.51500V	0.5124V	1
	1	1	1	1	1	1	0.41200V	0.4099V	1
	0	×	×	×	×	×	0.000V	×	1

## O PHYSICAL DIMENSIONS

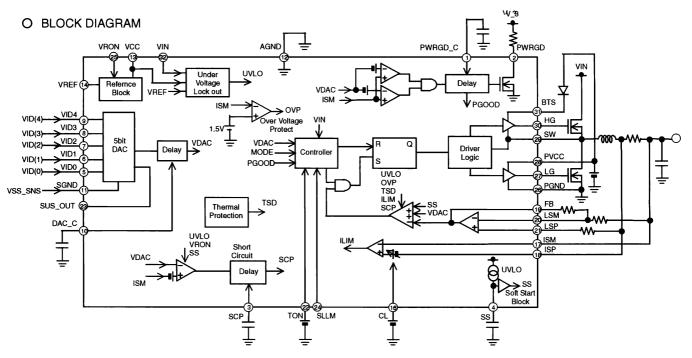


Pin No.	Pin name	Pin No.	Pin name
1	PWRGD_C	17	ISP
2	PWRGD	18	ISM
3	SCP	19	LSM
4	SS	20	LSP
5	VID0	21	FB
6	VID1	22	TON
7	VID2	23	SUS_OUT
8	VID3	24	SLLM
9	VID4	25	VRON
10	DAC_C	26	PGND
11	SGND	27	LG
12	GND	28	PVCC
13	VCC	29	SW
14	VREF	30	HG
15	NC	31	BTS
16	CL	32	VIN

VQFN032V5050

```
(Unit:mm)
```





#### **BD9560MUV BLOCK DIAGRAM**

## O NOTE FOR USE

(1) Absolute maximum rating

The device may be destroyed when applied voltage or operating temperature exceeds its absolute maximum rating. Because the source, such as short mode or open mode, cannot be identified if the device is destroyed, it is important to take physical safety measures (such as fusing) if a special mode in excess of absolute rating limits is to be implemented.

(2) Supply line

Since the motor's reverse electromotive force gives rise to the return of regenerative current, measures should be taken to establish a channel for the current, such as adding a capacitor between the power supply and GND. In determining the approach to take, make sure that no problems will be posed by the various characteristics involved, such as capacitance loss at low temperatures with an electrolytic capacitor.

(3) GND potential

Make sure the potential for the GND pin is always kept lower than the potentials of all other pins, regardless of the operating mode.

(4) Thermal design

Be sure to factor in allowable power dissipation (Pd) in actual operation, and to build sufficient margin into the thermal design to accommodate this power loss.

- (5) Operation in strong magnetic fields
- Use in strong electromagnetic fields may cause malfunctions. Exercise caution with respect to electromagnetic fields.
- (6) ASO

Set the parameters so that output Tr will not exceed the absolute maximum rating or ASO value when the IC is used.

(7) Thermal shutdown circuit

This IC is provided with a built-in thermal shutdown (TSD) circuit, which is activated when the chip temperature reaches the threshold value listed below. When TSD is on, the device goes to high impedance mode. Note that the TSD circuit is provided for the exclusive purpose shutting down the IC in the presence of extreme heat, and is not designed to protect the IC per se or guarantee performance when or after extreme heat conditions occur. Therefore, do not operate the IC with the expectation of continued use or subsequent operation once the TSD is activated.

TSD ON temperature [°C] (typ.)	Hysteresis temperature[°C] (typ.)
175	15

wiring pattern

(8) Ground

When both a small-signal GND and high current GND are present, single-point grounding (at the set standard point) is recommended, in order to separate the small-signal and high current patterns, and to be sure the voltage change stemming from the wiring resistance and high current does not cause any voltage change in the small-signal GND. In the same way, care must be taken to avoid wiring pattern fluctuations in any connected external component GND.

(9) Heat sink (FIN)

Since the heat sink (FIN) is connected with the Sub, short it to the GND.

(10) Short-circuits between pins and and mounting errors

When mounting the IC onto a set substrate or circuit board, be careful to avoid incorrect orientation or mis-positioning of the IC, as such mounting errors may cause device malfunctions. Similar damage may occur when the power supply connection is reversed. Also, note that the introduction of foreign material between pins and the GND, or between the pins themselves may cause shorts and destroy the IC.

4/4

## Appendix

## Notes No technical content pages of this document may be reproduced in any form or transmitted by any means without prior permission of ROHM CO., LTD. The contents described herein are subject to change without notice. The specifications for the product described in this document are for reference only. Upon actual use, therefore, please request that specifications to be separately delivered. Application circuit diagrams and circuit constants contained herein are shown as examples of standard use and operation. Please pay careful attention to the peripheral conditions when designing circuits and deciding upon circuit constants in the set. Any data, including, but not limited to application circuit diagrams information, described herein are intended only as illustrations of such devices and not as the specifications for such devices. ROHM CO.,LTD. disclaims any warranty that any use of such devices shall be free from infringement of any third party's intellectual property rights or other proprietary rights, and further, assumes no liability of whatsoever nature in the event of any such infringement, or arising from or connected with or related to the use of such devices. Upon the sale of any such devices, other than for buyer's right to use such devices itself, resell or otherwise dispose of the same, no express or implied right or license to practice or commercially exploit any intellectual property rights or other proprietary rights owned or controlled by ROHM CO., LTD. is granted to any such buyer. Products listed in this document are no antiradiation design. The products listed in this document are designed to be used with ordinary electronic equipment or devices (such as audio visual equipment, office-automation equipment, communications devices, electrical appliances and electronic toys). Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

About Export Control Order in Japan

Products described herein are the objects of controlled goods in Annex 1 (Item 16) of Export Trade Control Order in Japan.

In case of export from Japan, please confirm if it applies to "objective" criteria or an "informed" (by MITI clause) on the basis of "catch all controls for Non-Proliferation of Weapons of Mass Destruction.

Thank you for your accessing to ROHM product informations. More detail product informations and catalogs are available, please contact your nearest sales office.

Please contact our sales offices for details ;

U.S.A / San Diego Atlanta Dallas	TEL : +1(858)625-3630 TEL : +1(770)754-5972 TEL : +1(972)312-8818	FAX : +1(858)625-3670 FAX : +1(770)754-0691 FAX : +1(972)312-0330
Germany / Dusseldorf	TEL : +49(2154)9210	FAX : +49(2154)921400
United Kingdom / London	TEL:+44(1)908-282-666	FAX : +44(1)908-282-528
France / Paris	TEL : +33(0)1 56 97 30 60	FAX : +33(0) 1 56 97 30 80
China / Hong Kong Shanghai Dilian Beijing	TEL:+852(2)740-6262 TEL:+86(21)6279-2727 TEL:+86(411)8230-8549 TEL:+86(10)8525-2483	FAX : +852(2)375-8971 FAX : +86(21)6247-2066 FAX : +86(411)8230-8537 FAX : +86(10)8525-2489
Taiwan / Taipei	TEL : +866(2)2500-6956	FAX : +866(2)2503-2869
Korea / Seoul	TEL : +82(2)8182-700	FAX : +82(2)8182-715
Singapore	TEL : +65-6332-2322	FAX : +65-6332-5662
Malaysia / Kuala Lumpur	TEL : +60(3)7958-8355	FAX : +60(3)7958-8377
Philippines / Manila	TEL : +63(2)807-6872	FAX : +63(2)809-1422
Thailand / Bangkok	TEL:+66(2)254-4890	FAX : +66(2)256-6334

#### Japan /

(Internal Sales	3)				
Tokyo	2-1-1, Yaesu, Chuo-ku, Tokyo 104-0082 TEL : +81(3)5203-0321 FAX : +81(3)5203-0300				
Yokohama	2-4-8, Shin Yokohama, Kohoku-ku, Yokohama, Kanagawa 222-8575 TEL : +81(45)476-2131 FAX : +81(45)476-2128				
Nagoya	Dainagayo Building 9F 3-28-12, Meieki, Nakamura-ku, Nagoya, Aichi 450-0002 TEL : +81(52)581-8521 FAX : +81(52)561-2173				
Kyoto	579-32 Higashi Shiokouji-cho, Karasuma Nishi-iru, Shiokoujidori, Shimogyo-ku, Kyoto 600-8216 TEL : +81(75)311-2121 FAX : +81(75)314-6559				
(Contact address for overseas customers in Japan)					
Yokohama	TEL : +81(45)476-9270 FAX : +81(045)476-9271				